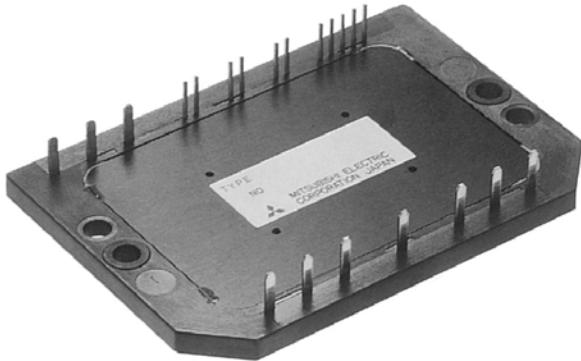


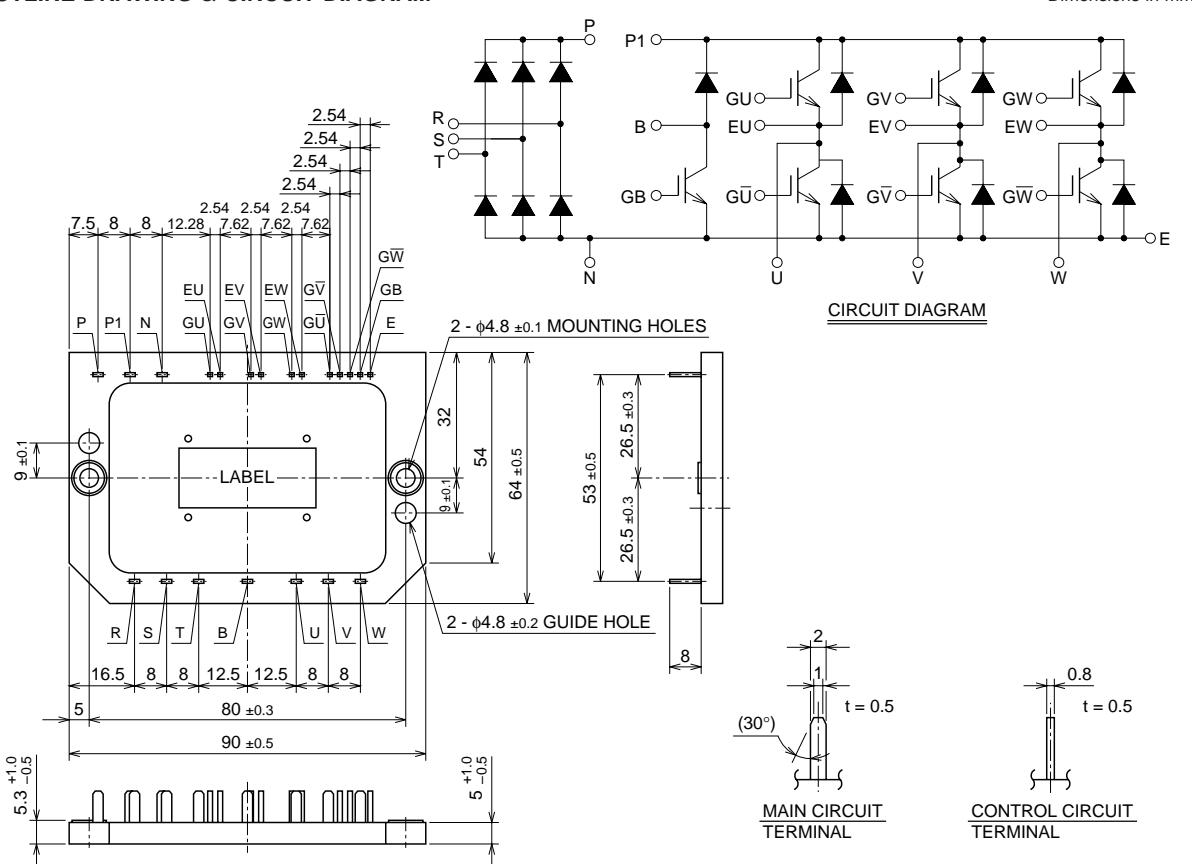
**CM10MD-24H**

- $I_c$  ..... 10A
- $V_{CES}$  ..... 1200V
- Insulated Type
- CIB Module
- 3φ Inverter+3φ Converter+Brake
- UL Recognized

Yellow Card No. E80276 (N)  
File No. E80271

**APPLICATION**

AC & DC motor controls, General purpose inverters, Servo controls, NC, Robotics

**OUTLINE DRAWING & CIRCUIT DIAGRAM**

**CM10MD-24H**

**MEDIUM POWER SWITCHING USE  
INSULATED TYPE**

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**MAXIMUM RATINGS ( $T_j = 25^\circ\text{C}$ )  
INVERTER PART**

Symbol	Parameter	Condition	Rating	Unit
V <sub>CES</sub>	Collector-emitter voltage	G – E Short	1200	V
V <sub>GES</sub>	Gate-emitter voltage	C – E Short	±20	V
I <sub>C</sub>	Collector Current	$T_C = 25^\circ\text{C}$	10	A
I <sub>CM</sub>		PULSE (Note. 2)	20	A
I <sub>E</sub> (Note. 1)	Emitter Current	$T_C = 25^\circ\text{C}$	10	A
I <sub>EM</sub> (Note. 1)		PULSE (Note. 2)	20	A
P <sub>C</sub> (Note. 3)	Maximum collector dissipation	$T_f = 25^\circ\text{C}$	57	W

**BRAKE PART**

Symbol	Parameter	Condition	Rating	Unit
V <sub>CES</sub>	Collector-emitter voltage	G – E Short	1200	V
V <sub>GES</sub>	Gate-emitter voltage	C – E Short	±20	V
I <sub>C</sub>	Collector Current	$T_C = 25^\circ\text{C}$	10	A
I <sub>CM</sub>		PULSE (Note. 2)	20	A
P <sub>C</sub> (Note. 3)	Maximum Collector dissipation	$T_f = 25^\circ\text{C}$	57	W
V <sub>RRM</sub>	Repetitive peak reverse voltage	Clamp diode part	1200	V
I <sub>FM</sub> (Note. 3)	Forward current	Clamp diode part	10	A

**CONVERTER PART**

Symbol	Parameter	Condition	Rating	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage		1600	V
E <sub>a</sub>	Recommended AC input voltage		440	V
I <sub>O</sub>	DC output current	3φ rectifying circuit	10	A
I <sub>FSM</sub>	Surge (non-repetitive) forward current	1 cycle at 60Hz, peak value Non-repetitive	100	A
I <sup>2</sup> t	I <sup>2</sup> t for fusing	Value for one cycle of surge current	42	A <sup>2</sup> s

**COMMON RATING**

Symbol	Parameter	Condition	Rating	Unit
T <sub>j</sub>	Junction temperature		-40 ~ +150	°C
T <sub>stg</sub>	Storage temperature		-40 ~ +125	°C
V <sub>iso</sub>	Isolation voltage	AC 1 min.	2500	V
—	Mounting torque	Mounting M4 screw	1.47 ~ 1.96	N·m
—	Weight	Typical value	60	g

**ELECTRICAL CHARACTERISTICS** ( $T_j = 25^\circ\text{C}$ )  
**INVERTER PART**

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
ICES	Collector cutoff current	VCE = VCES, VGE = 0V	—	—	1	mA
VGE(th)	Gate-emitter threshold voltage	IC = 1.0mA, VCE = 10V	4.5	6	7.5	V
IGES	Gate-emitter cutoff current	VGE = VGES, VCE = 0V	—	—	0.5	$\mu\text{A}$
VCE(sat)	Collector-emitter saturation voltage	$T_j = 25^\circ\text{C}$	IC = 10A, VGE = 15V	(Note. 4)	2.7	3.4
		$T_j = 150^\circ\text{C}$			2.45	—
Cies	Input capacitance	VCE = 10V VGE = 0V	—	—	2.0	nF
Coes	Output capacitance		—	—	1.5	nF
Cres	Reverse transfer capacitance		—	—	0.4	nF
QG	Total gate charge	VCC = 600V, IC = 10A, VGE = 15V	—	50	—	nC
td (on)	Turn-on delay time	VCC = 600V, IC = 10A	—	—	100	ns
tr	Turn-on rise time	VGE1 = VGE2 = 15V	—	—	200	ns
td (off)	Turn-off delay time	RG = 31Ω	—	—	150	ns
tf	Turn-off fall time	Resistive load	—	—	350	ns
VEC (Note. 1)	Emitter-collector voltage	IE = 10A, VGE = 0V	—	—	3.5	V
trr (Note. 1)	Reverse recovery time	IE = 10A, VGE = 0V die / dt = -20A / $\mu\text{s}$	—	—	250	ns
Qrr (Note. 1)	Reverse recovery charge		—	0.08	—	$\mu\text{C}$
Rth(j-f)Q (Note. 5)	Thermal resistance	IGBT part, Per 1/6 module	—	—	2.2	$^\circ\text{C}/\text{W}$
		FWDi part, Per 1/6 module	—	—	3.1	$^\circ\text{C}/\text{W}$

**BRAKE PART**

Symbol	Parameter	Condition	Limits			Unit
			Min.	Typ.	Max.	
ICES	Collector cutoff current	VCE = VCES, VGE = 0V	—	—	1	mA
VGE(th)	Gate-emitter threshold voltage	IC = 1.0mA, VCE = 10V	4.5	6	7.5	V
IGES	Gate-emitter cutoff current	VGE = VGES, VCE = 0V	—	—	0.5	$\mu\text{A}$
VCE(sat)	Collector-to-emitter saturation voltage	$T_j = 25^\circ\text{C}$	IC = 10A, VGE = 15V	(Note. 4)	2.7	3.4
		$T_j = 150^\circ\text{C}$			2.45	—
Cies	Input capacitance	VCE = 10V VGE = 0V	—	—	2.0	nF
Coes	Output capacitance		—	—	1.5	nF
Cres	Reverse transfer capacitance		—	—	0.4	nF
QG	Total gate charge	VCC = 600V, IC = 10A, VGE = 15V	—	50	—	nC
VFM	Forward voltage drop	IF = 10A, Clamp diode part	—	—	1.7	V
Rth(j-f)Q (Note. 5)	Thermal resistance	IGBT part	—	—	2.2	$^\circ\text{C}/\text{W}$
		Clamp diode part	—	—	2.7	$^\circ\text{C}/\text{W}$

**CONVERTER PART**

Symbol	Parameter	Condition	Limits			Unit
			Min.	Typ.	Max.	
IRR	Repetitive reverse current	VR = VRMM, $T_j = 150^\circ\text{C}$	—	—	8	mA
VFM	Forward voltage drop	IF = 10A	—	—	1.7	V
Rth(j-f) (Note. 5)	Thermal resistance	Per 1/6 module	—	—	2.7	$^\circ\text{C}/\text{W}$

Note 1. IE, VEC, trr, Qrr &amp; die/dt represent characteristics of the anti-parallel, emitter to collector free-wheel diode.

2. Pulse width and repetition rate should be such that the device junction temp. ( $T_j$ ) does not exceed  $T_{jmax}$  rating.3. Junction temperature ( $T_j$ ) should not increase beyond  $150^\circ\text{C}$ .

4. Pulse width and repetition rate should be such as to cause negligible temperature rise.

5. Thermal resistance is specified under following conditions.

• The conductive grease applied, between module and fin.

• Al plate is used as fin.